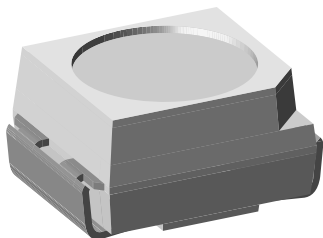




## Power SMD LED PLCC-2



19225

### DESCRIPTION

The VLM.334.. series is an advanced modification of the Vishay VLM.31.. series. It is designed to incorporate larger chips, therefore, capable of withstanding a 70 mA drive current.

The package of the VLM.334.. is the PLCC-2.

It consists of a lead frame which is embedded in a white thermoplast. The reflector inside this package is filled up with clear epoxy.

### PRODUCT GROUP AND PACKAGE DATA

- Product group: LED
- Package: SMD PLCC-2
- Product series: power
- Angle of half intensity:  $\pm 60^\circ$

### FEATURES

- Utilizing latest advanced AllnGaP technology
- Available in 8 mm tape
- Luminous intensity and color categorized per packing unit
- Luminous intensity ratio per packing unit  $I_{Vmax}/I_{Vmin.} \leq 1.6$
- Thermal resistance  $R = 300$  K/W
- ESD-withstand voltage: Up to 2 kV according to JESD22-A114-B
- Preconditioning according to JEDEC level 2a
- Compatible with reflow, vapor phase and wave solder processes according to CECC 00802 and J-STD-020
- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



### APPLICATIONS

- Traffic signals and signs
- Interior and exterior lighting
- Dashboard illumination
- Indicator and backlighting purposes for audio, video, LCDs switches, symbols, illuminated advertising etc.

PARTS TABLE														
PART	COLOR	LUMINOUS INTENSITY (mcd)			at $I_F$ (mA)	WAVELENGTH (nm)			at $I_F$ (mA)	FORWARD VOLTAGE (V)			at $I_F$ (mA)	TECHNOLOGY
		MIN.	TYP.	MAX.		MIN.	TYP.	MAX.		MIN.	TYP.	MAX.		
VLMS334AABB-GS08	Super red	1120	1600	2800	50	626	630	639	50	1.9	2.2	2.8	50	AllnGaP on Si
VLMS334AABB-GS18	Super red	1120	1600	2800	50	626	630	639	50	1.9	2.2	2.8	50	AllnGaP on Si
VLMR334BACB-GS08	Red	1800	2200	4500	50	619	625	631	50	1.9	2.2	2.8	50	AllnGaP on Si
VLMR334BACB-GS18	Red	1800	2200	4500	50	619	625	631	50	1.9	2.2	2.8	50	AllnGaP on Si
VLMK334BACB-GS08	Amber	1800	2800	4500	50	611	616	622	50	1.9	2.25	2.8	50	AllnGaP on Si
VLMK334BACB-GS08	Amber	1800	2800	4500	50	611	616	622	50	1.9	2.25	2.8	50	AllnGaP on Si
VLMY334BACB-GS08	Yellow	1800	2300	4500	50	583	589	594	50	1.9	2.3	2.8	50	AllnGaP on Si
VLMY334BACB-GS18	Yellow	1800	2300	4500	50	583	589	594	50	1.9	2.3	2.8	50	AllnGaP on Si

ABSOLUTE MAXIMUM RATINGS ( $T_{amb} = 25^\circ\text{C}$ , unless otherwise specified)				
VLMS334..., VLMR334..., VLMK334..., VLMY334...				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage <sup>(1)</sup>	Short term application only	$V_R$	5	V
DC forward current	$T_{amb} \leq 60^\circ\text{C}$ (400 K/W)	$I_F$	70	mA
Power dissipation		$P_V$	200	mW
Junction temperature		$T_j$	125	$^\circ\text{C}$
Operating temperature range		$T_{amb}$	- 40 to + 100	$^\circ\text{C}$
Storage temperature range		$T_{stg}$	- 40 to + 100	$^\circ\text{C}$
Thermal resistance junction/ambient	Mounted on PC board (pad size > 16 mm <sup>2</sup> )	$R_{thJA}$	300	K/W

**Note**

<sup>(1)</sup> Driving the LED in reverse direction is suitable for a short term application

**OPTICAL AND ELECTRICAL CHARACTERISTICS** ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)  
**VLMS334.., SUPER RED**

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	$I_F = 50\text{ mA}$	VLMS334AABB	$I_V$	1120	1600	2800	mcd
Luminous flux/luminous intensity			$\phi_V/I_V$	-	3	-	mlm/mcd
Dominant wavelength	$I_F = 50\text{ mA}$		$\lambda_d$	626	630	639	nm
Peak wavelength	$I_F = 50\text{ mA}$		$\lambda_p$	-	639	-	nm
Spectral bandwidth at 50 % $I_{rel\ max.}$	$I_F = 50\text{ mA}$		$\Delta\lambda$	-	18	-	nm
Angle of half intensity	$I_F = 50\text{ mA}$		$\phi$	-	$\pm 60$	-	deg
Forward voltage	$I_F = 50\text{ mA}$		$V_F$	1.9	2.2	2.8	V
Reverse current	$V_R = 5\text{ V}$		$I_R$	-	0.01	10	$\mu\text{A}$

**OPTICAL AND ELECTRICAL CHARACTERISTICS** ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)  
**VLMR334.., RED**

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	$I_F = 50\text{ mA}$	VLMR334BACB	$I_V$	1800	2200	4500	mcd
Luminous flux/luminous intensity			$\phi_V/I_V$	-	3	-	mlm/mcd
Dominant wavelength	$I_F = 50\text{ mA}$		$\lambda_d$	619	625	631	nm
Peak wavelength	$I_F = 50\text{ mA}$		$\lambda_p$	-	632	-	nm
Spectral bandwidth at 50 % $I_{rel\ max.}$	$I_F = 50\text{ mA}$		$\Delta\lambda$	-	18	-	nm
Angle of half intensity	$I_F = 50\text{ mA}$		$\phi$	-	$\pm 60$	-	deg
Forward voltage	$I_F = 50\text{ mA}$		$V_F$	1.9	2.2	2.8	V
Reverse current	$V_R = 5\text{ V}$		$I_R$	-	0.01	10	$\mu\text{A}$

**OPTICAL AND ELECTRICAL CHARACTERISTICS** ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)  
**VLMK334.., AMBER**

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	$I_F = 50\text{ mA}$	VLMK334BACB	$I_V$	1800	2800	4500	mcd
Luminous flux/luminous intensity			$\phi_V/I_V$	-	3	-	mlm/mcd
Dominant wavelength	$I_F = 50\text{ mA}$		$\lambda_d$	611	616	622	nm
Peak wavelength	$I_F = 50\text{ mA}$		$\lambda_p$	-	622	-	nm
Spectral bandwidth at 50 % $I_{rel\ max.}$	$I_F = 50\text{ mA}$		$\Delta\lambda$	-	18	-	nm
Angle of half intensity	$I_F = 50\text{ mA}$		$\phi$	-	$\pm 60$	-	deg
Forward voltage	$I_F = 50\text{ mA}$		$V_F$	1.9	2.25	2.8	V
Reverse current	$V_R = 5\text{ V}$		$I_R$	-	0.01	10	$\mu\text{A}$

**OPTICAL AND ELECTRICAL CHARACTERISTICS** ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)  
**VLMY334.., YELLOW**

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	$I_F = 50\text{ mA}$	VLMY334BACB	$I_V$	1800	2300	4500	mcd
Luminous flux/luminous intensity			$\phi_V/I_V$	-	3	-	mlm/mcd
Dominant wavelength	$I_F = 50\text{ mA}$		$\lambda_d$	583	589	594	nm
Peak wavelength	$I_F = 50\text{ mA}$		$\lambda_p$	-	591	-	nm
Spectral bandwidth at 50 % $I_{rel\ max.}$	$I_F = 50\text{ mA}$		$\Delta\lambda$	-	17	-	nm
Angle of half intensity	$I_F = 50\text{ mA}$		$\phi$	-	$\pm 60$	-	deg
Forward voltage	$I_F = 50\text{ mA}$		$V_F$	1.9	2.3	2.8	V
Reverse current	$V_R = 5\text{ V}$		$I_R$	-	0.01	10	$\mu\text{A}$



COLOR CLASSIFICATION				
GROUP	DOM. WAVELENGTH (nm)			
	AMBER		YELLOW	
	MIN.	MAX.	MIN.	MAX.
1	611	618		
2	614	622	583	586
3			585	588
4			587	590
5			589	592
6			591	594

**Note**

- Wavelengths are tested at a current pulse duration of 25 ms.

LUMINOUS INTENSITY CLASSIFICATION		
GROUP	LIGHT INTENSITY (mcd)	
	MIN.	MAX.
STANDARD		
AA	1120	1400
AB	1400	1800
BA	1800	2240
BB	2240	2800
CA	2800	3550
CB	3550	4500

CROSSING TABLE	
VISHAY	OSRAM
VLMS334AABB	LS T67F-T2V2-1-1
VLMR334BACB	LR T67F-U1AA-1-1
VLMK334BACB	LA T67F-U2AB-24-1
VLMY334BACB	LY T67F-U1AA-36-1

**Note**

- Luminous intensity is tested at a current pulse duration of 25 ms and an accuracy of  $\pm 11\%$ .  
The above type numbers represent the order groups which include only a few brightness groups. Only one group will be shipped on each reel (there will be no mixing of two groups on each reel).  
In order to ensure availability, single brightness groups will not be orderable.  
In a similar manner for colors where wavelength groups are measured and binned, single wavelength groups will be shipped on any one reel.  
In order to ensure availability, single wavelength groups will not be orderable.



**TYPICAL CHARACTERISTICS** ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)

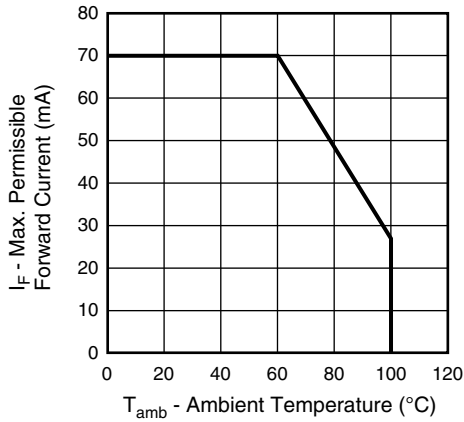


Fig. 1 - Maximum Permissible Forward Current vs. Ambient Temperature

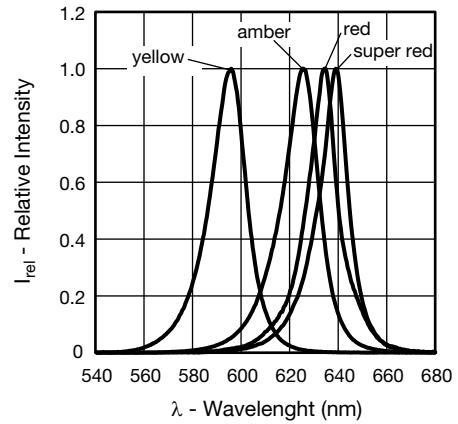


Fig. 4 - Relative Intensity vs. Wavelength

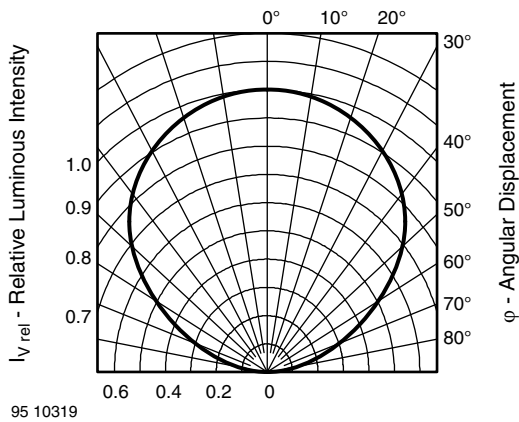


Fig. 2 - Relative Luminous Intensity vs. Angular Displacement

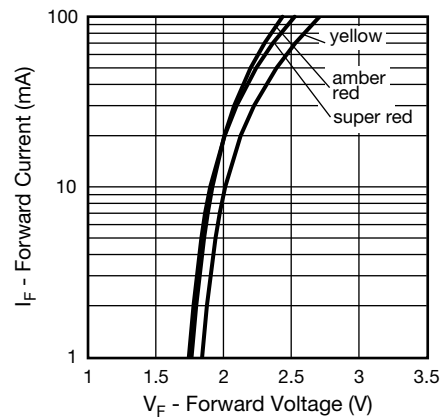


Fig. 5 - Forward Current vs. Forward Voltage

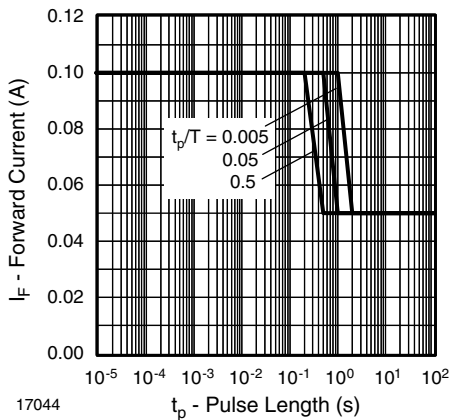


Fig. 3 - Forward Current vs. Pulse Length

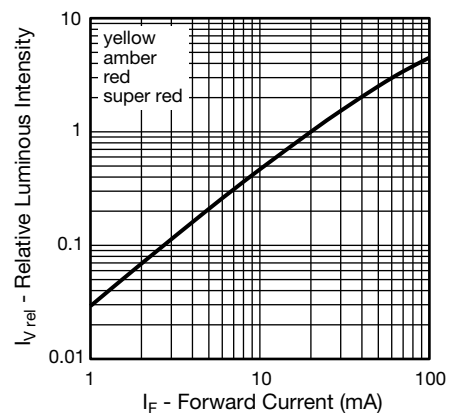


Fig. 6 - Relative Luminous Intensity vs. Forward Current

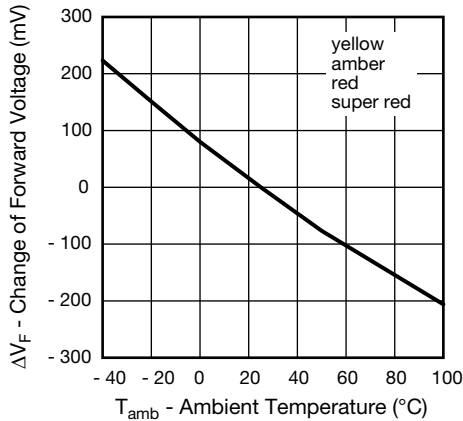


Fig. 7 - Change of Forward Voltage vs. Ambient Temperature

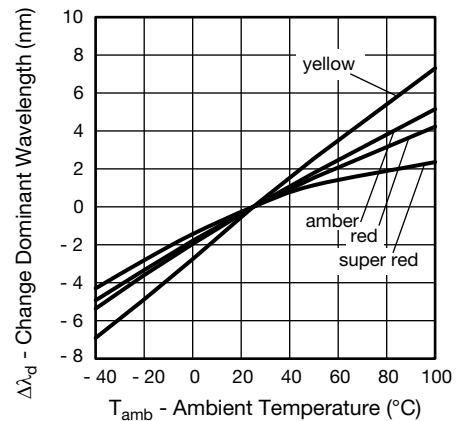


Fig. 9 - Change of Dominant Wavelength vs. Ambient Temperature

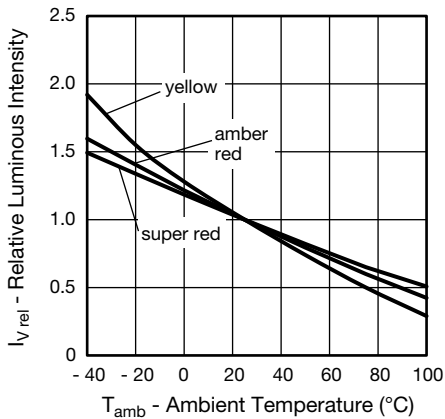
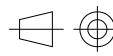
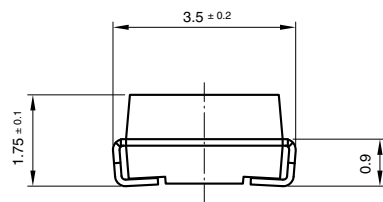
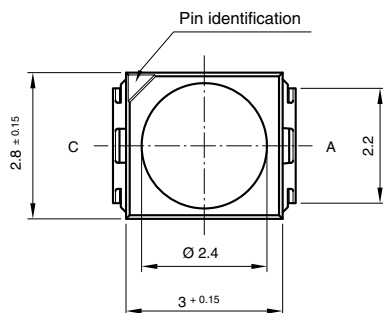


Fig. 8 - Relative Luminous Intensity vs. Ambient Temperature

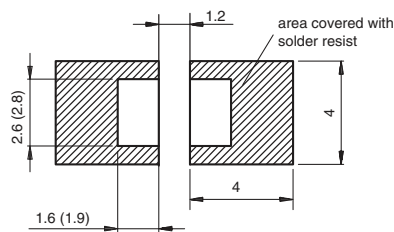
**PACKAGE DIMENSIONS** in millimeters



technical drawings according to DIN specifications



**Mounting Pad Layout**



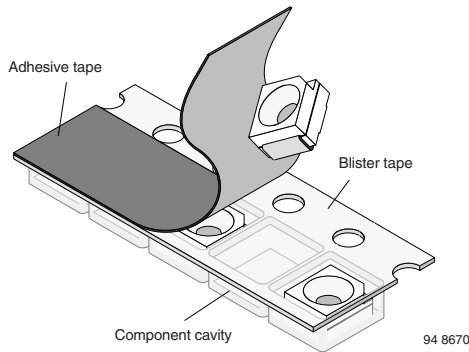
Drawing-No.: 6.541-5067.01-4  
Issue: 5; 04.11.08  
20541



**METHOD OF TAPING/POLARITY AND TAPE AND REEL**

**SMD LED (VLMx334..-SERIES)**

Vishay's LEDs in SMD packages are available in an antistatic 8 mm blister tape (in accordance with DIN IEC 40 (CO) 564) for automatic component insertion. The blister tape is a plastic strip with impressed component cavities, covered by a top tape.



**REEL PACKAGE DIMENSION IN MILLIMETERS FOR SMD LEDs, TAPE OPTION GS18 (= 8000 PCS.) PREFERRED**

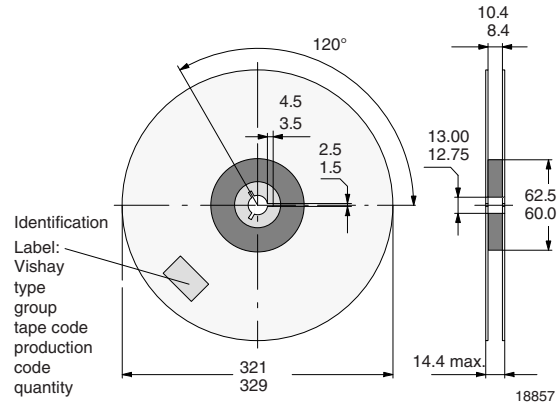


Fig. 12 - Reel Dimensions - GS18

**TAPING OF VLMx334..**

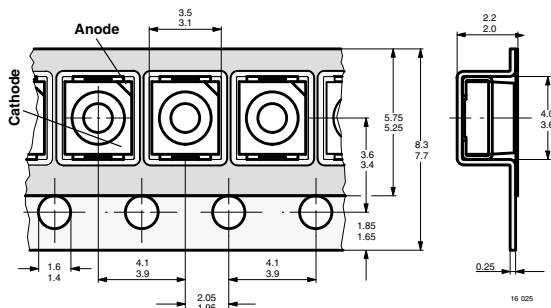


Fig. 10 - Tape Dimensions in mm for PLCC-2

**SOLDERING PROFILE**

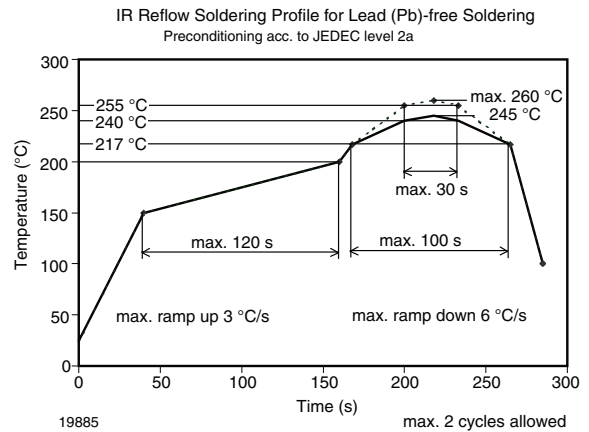


Fig. 13 - Vishay Lead (Pb)-free Reflow Soldering Profile (acc. to J-STD-020)

**REEL PACKAGE DIMENSION IN MILLIMETERS FOR SMD LEDs, TAPE OPTION GS08 (= 1500 PCS.)**

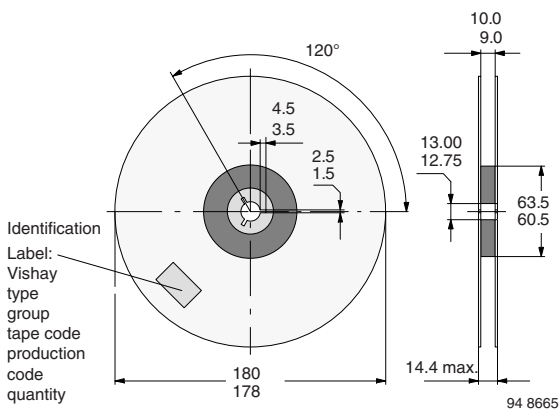


Fig. 11 - Reel Dimensions - GS08

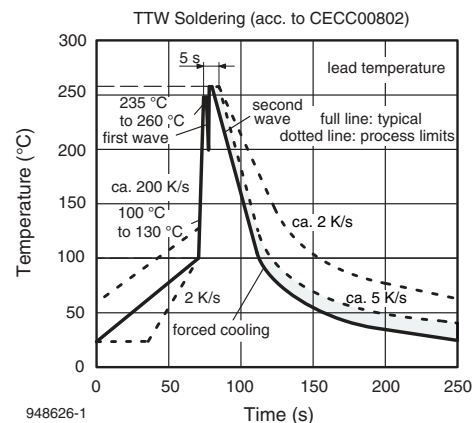
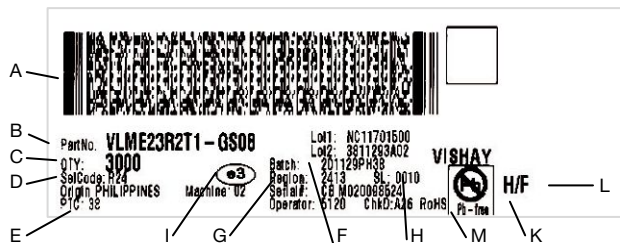


Fig. 14 - Double Wave Soldering of Opto Devices (all Packages)



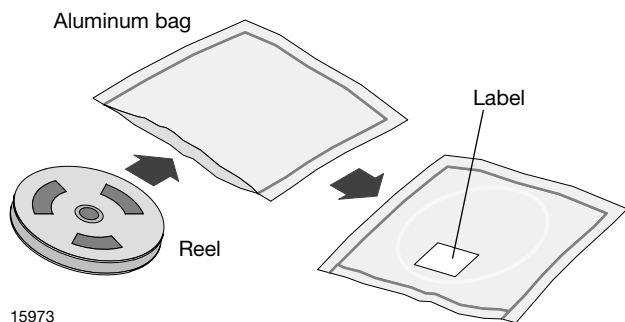
**BAR CODE PRODUCT LABEL** (example only)



- A. 2D barcode
- B. Vishay part number
- C. Quantity
- D. PTC = selection code (binning)
- E. Code of manufacturing plant
- F. Batch = date code: year/week/plant code
- G. Region code
- H. SL = sales location
- I. Terminations finishing
- K. Lead (Pb)-free symbol
- L. Halogen-free symbol
- M. RoHS symbol

**DRY PACKING**

The reel is packed in an anti-humidity bag to protect the devices from absorbing moisture during transportation and storage.



15973

**FINAL PACKING**

The sealed reel is packed into a cardboard box. A secondary cardboard box is used for shipping purposes.

**RECOMMENDED METHOD OF STORAGE**

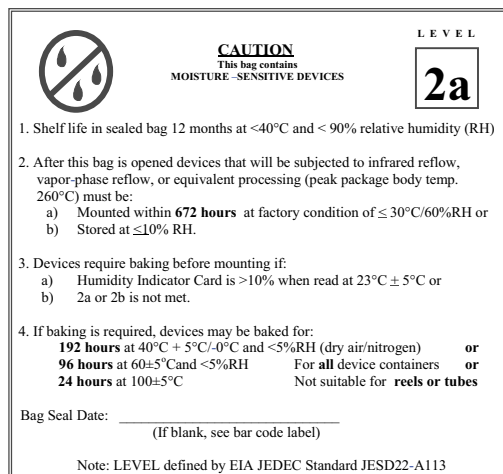
Dry box storage is recommended as soon as the aluminum bag has been opened to prevent moisture absorption. The following conditions should be observed, if dry boxes are not available:

- Storage temperature 10 °C to 30 °C
- Storage humidity ≤ 60 % RH max.

After more than 672 h under these conditions moisture content will be too high for reflow soldering.

In case of moisture absorption, the devices will recover to the former condition by drying under the following condition:  
 192 h at 40 °C + 5 °C/- 0 °C and < 5 % RH (dry air/nitrogen) or  
 96 h at 60 °C + 5 °C and < 5 % RH for all device containers or  
 24 h at 100 °C + 5 °C not suitable for reel or tubes.

An EIA JEDEC standard JESD22-A112 level 2a label is included on all dry bags.



Example of JESD22-A112 level 2a label

**ESD PRECAUTION**

Proper storage and handling procedures should be followed to prevent ESD damage to the devices especially when they are removed from the antistatic shielding bag. Electro-static sensitive devices warning labels are on the packaging.

**VISHAY SEMICONDUCTORS STANDARD BAR CODE LABEL**

The Vishay Semiconductors standard bar code labels are printed at final packing areas. The labels are on each packing unit and contain Vishay Semiconductors specific data.

Компания «Океан Электроники» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Поставка оригинальных импортных электронных компонентов напрямую с производств Америки, Европы и Азии, а так же с крупнейших складов мира;
- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «JONHON», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «FORSTAR».



## JONHON

«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели,  
кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



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Электронная почта: [ocean@oceanchips.ru](mailto:ocean@oceanchips.ru)

Web: <http://oceanchips.ru/>

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